SGS-THOMSON MICROELECTRONICS

TDA7332

RDS FILTER

ADVANCE DATA

- HIGH PERFORMANCE, STABLE 57KHz FILTER
- HIGH SELECTIVITY
- FLAT GROUP DELAY
- HIGH PERFORMANCE LIMITER
- VERY FEW EXTERNAL COMPONENTS
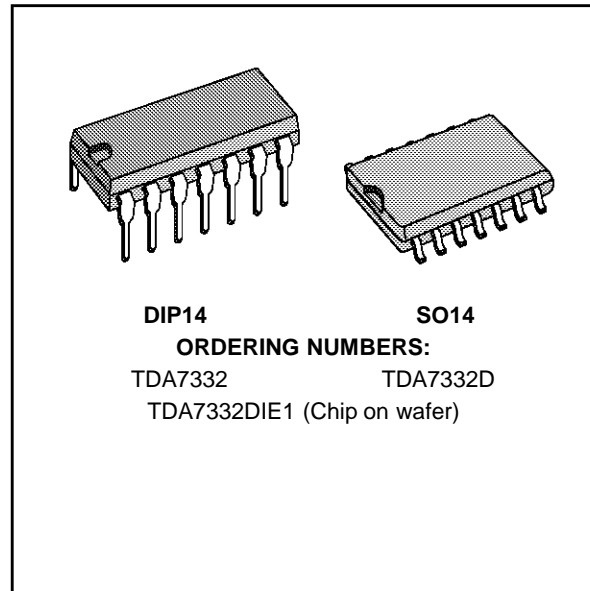- 4.332MHz CLOCK OSCILLATOR (8.664MHz OPTIONAL)

DESCRIPTION

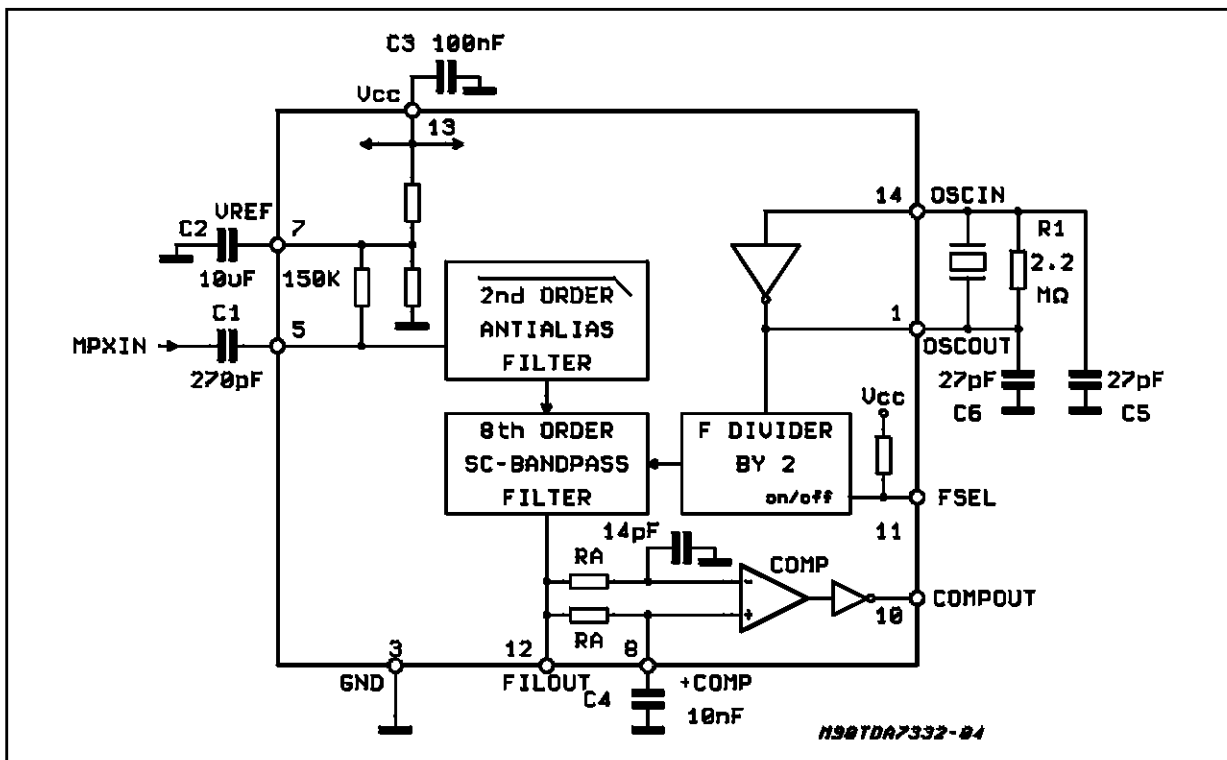The TDA7332 is an RDS filter, realized in switched capacitor technique.

The 4 biquad stage architecture is working with 4.332MHz clock.

Optionally a 8.664MHz xtal can be used.

The filter has a center frequency of 57KHz and a bandwidth of 3KHz. Input 2nd order antialiasing filter and output smoothing filter are provided.
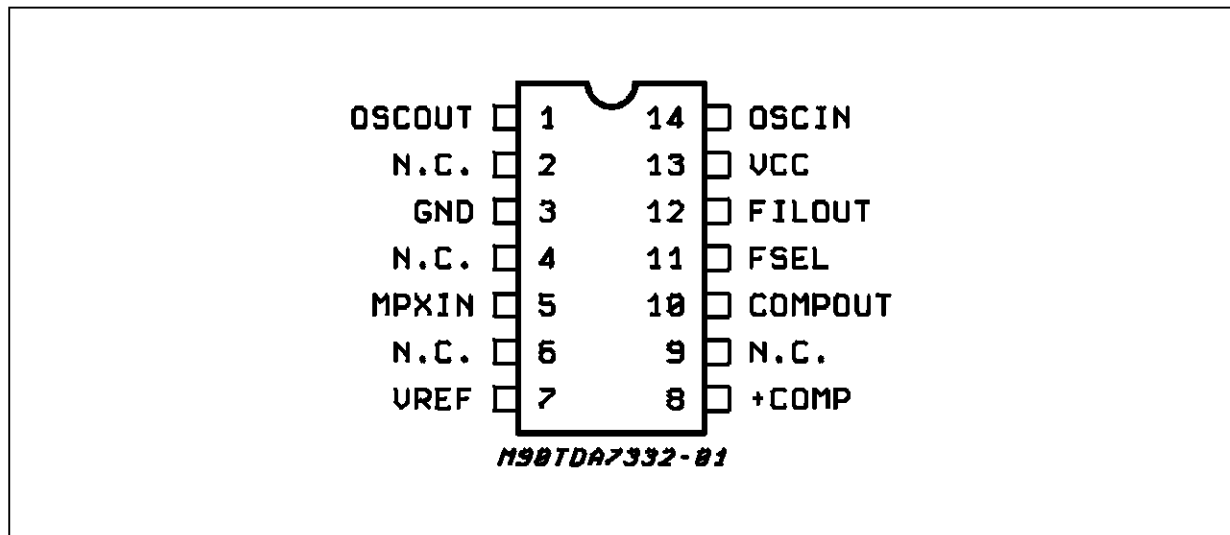
DIP14	SO14

ORDERING NUMBERS:

TDA7332   TDA7332D

TDA7332DIE1 (Chip on wafer)

TEST CIRCUIT

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage	7	V
T_{op}	Operating Temperature Range	-40 to 85	°C
T_{stg}	Storage Temperature	-40 to 150	°C

THERMAL DATA

Symbol	Description		DIP14	SO14	Unit
$R_{th\ j\text{-case}}$	Thermal Resistance Junction-case	Typ.	100	200	°C/W

PIN CONNECTION (Top view)

BONDING PAD LOCATIONS (Top view)

ELECTRICAL CHARACTERISTICS (V_{CC} = 5V, Tamb = 25°C; fosc = 4.332MHz; V_{IN} = 20mVrms unless otherwise specified)

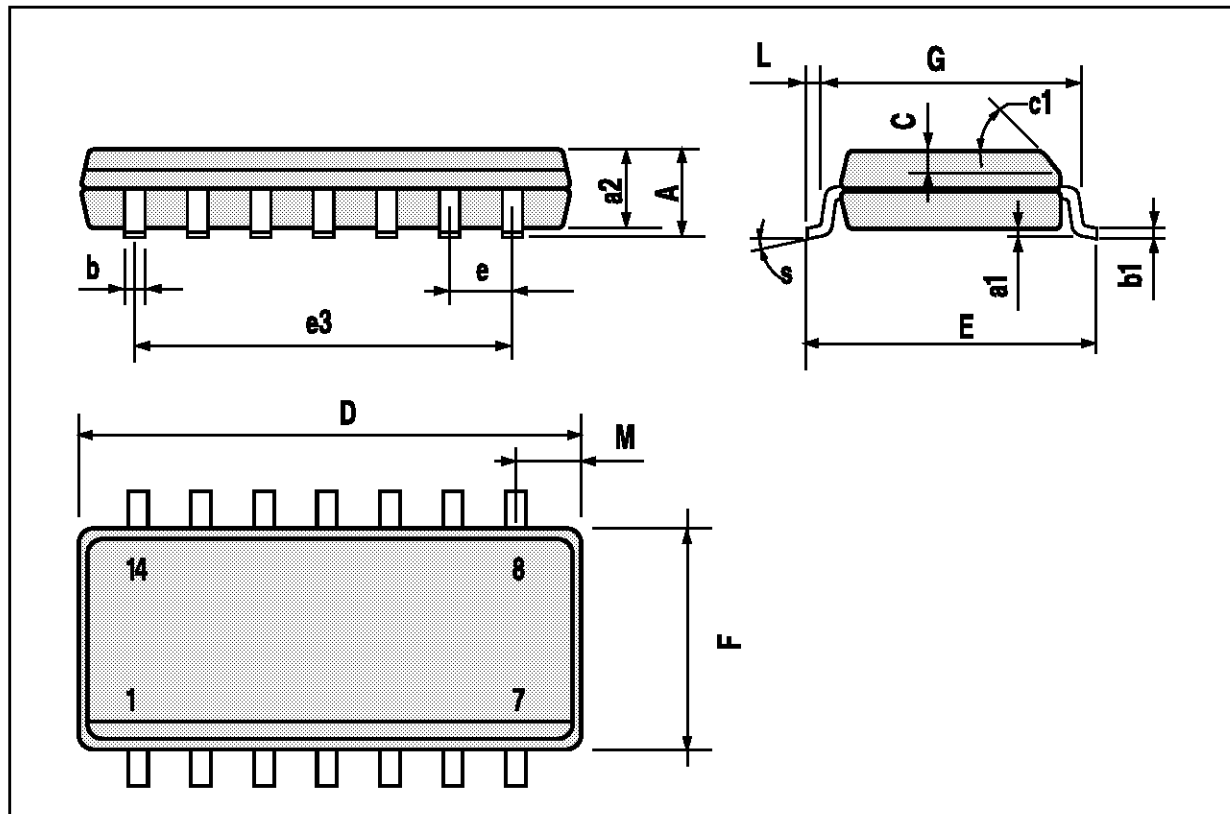| Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
SUPPLY SECTION						
V_{CC}	Supply Voltage		4.5	5	5.5	V
I_S	Supply Current		6	9	14	mA
FILTER						
F_C	Center Frequency		56.5	57	57.5	KHz
BW	3dB Bandwidth		2.5	3	3.5	KHz
G	Gain	f = 57KHz	18	20	22	dB
A	Attenuation	Δf = ±4KHz f = 38KHz; V_i = 500mVrms f = 67KHz; V_i = 250mVrms	18 50 35	22 80 50		dB dB dB
ΔPh	Phase non linearity	A (see note1) B (see note1) C (see note1)		0.5 1 2	5 7.5 10	DEG DEG DEG
R_i	Input Impedance		100	160	200	KΩ
S/N	Signal to Noise Ratio	V_i = 3mVrms	30	40		dB
V_i	Input Signal	f = 19KHz; T3 $\leq$ −40dB (see note2) f = 57KHz (RDS + ARI)			1 50	Vrms mVrms
R_L	Load Impedance	Pin 12	100			KΩ
LIMITER						
RA	Resistance pin 8-12		15	21	28	KΩ
V_{OL}	Comp. Output LOW	I_O = +0.5mA			1	V
V_{OH}	Comp. Output HIGH	IO = −0.5mA	4			V
	Duty Cycle	V_i = 1mVrms		50		%
OSCILLATOR						
F_{OSC}	Oscillator Frequency	F_{SEL} = Open F_{SEL} = Closed to Ground		4.332 8.664		MHz MHz
	Output Amplitude			5		V_{PP}
V_{CLL}	Clock Input Level LOW				1	V
V_{OLH}	Clock Input Level HIGH		4			V

CRYSTAL TYPE = EURO QUARTZ

Note (1):
The phase non linearity is defined as: ΔPh = | -2 ϕf2 + ϕf1 + ϕf3 |
where ϕfx is the input-output phase difference at the frequency fx (x = 1,2,3)

Measure	f1 (KHz)	f2 (KHz)	f3 (KHz)	ΔPh max
A	56.5	57	57.5	<5°
B	56	57	58	<7.5°
C	55.5	57	58.5	<10°

Note (2): The 3th harmonic (57KHz) at the output (pin12) must be less than -40dB in respect to the input signal plus gain.
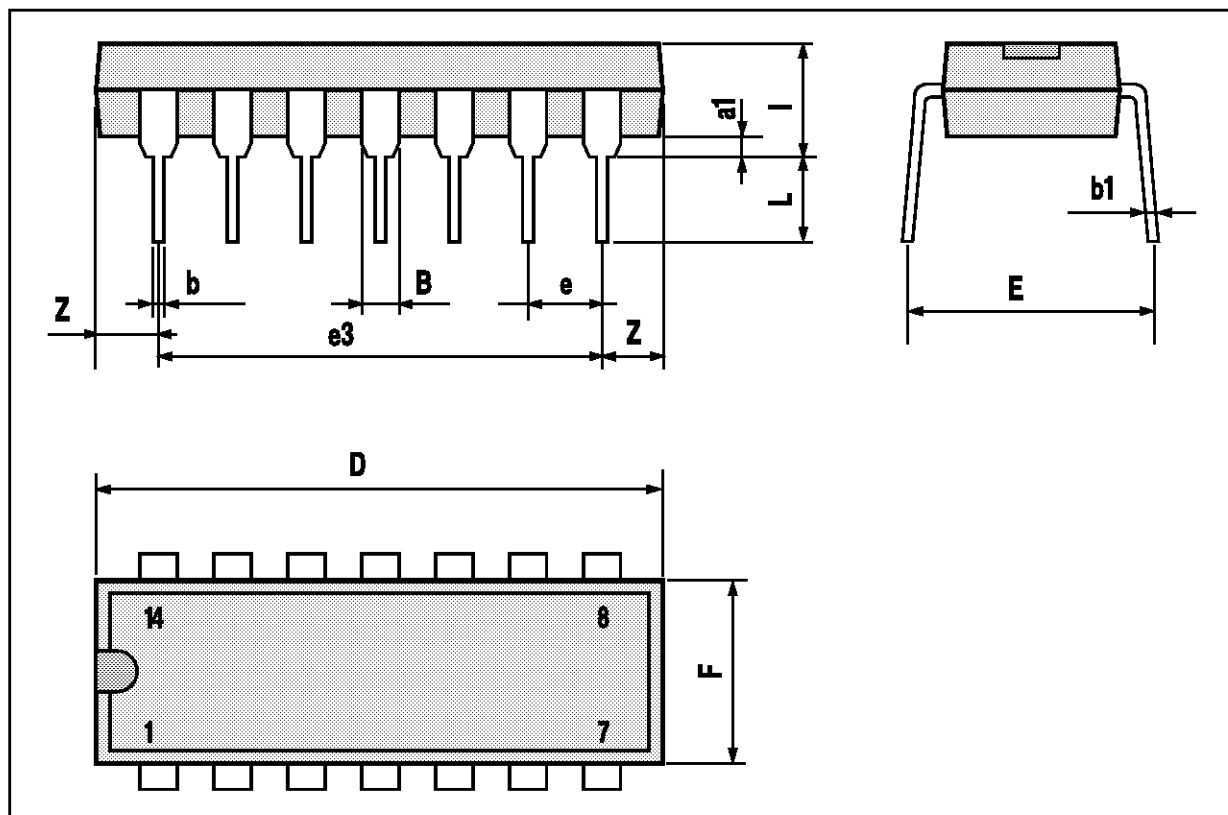
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SO14 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.069
a1	0.1		0.25	0.004		0.009
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45 (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.15		0.157
L	0.4		1.27	0.016		0.050
M			0.68			0.027
S	8 (max.)					

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DIP14 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

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